



### LOW DROPOUT LINEAR REGULATOR WITH INDUSTRIAL TEMPERATURE RANGE

### Description

The DIODES<sup>™</sup> AZ1117I is a low dropout three-terminal regulator optimized for a low voltage where transient response and minimum input voltage are critical. The device provides current-limit and thermal-shutdown features. Its circuit includes a trimmed bandgap reference to assure an output voltage accuracy of within ±1%. On-chip thermal shutdown provides protection against a combination of high current and ambient temperature that may create excessive junction temperature.

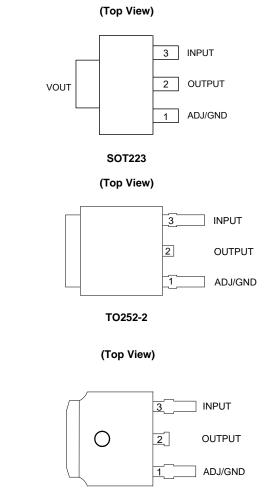
The AZ1117I is available in 1.2V, 1.5V, 1.8V, 2.5V, 3.3V, and 5.0V fixed output voltage versions and an ADJ output voltage version. The fixed versions integrate the adjust resistors. It is also available in an adjustable version which can set the output voltage with two external resistors.

The AZ1117I is available in the industry-standard SOT223 and TO252-2 packages.

### **Features**

- Current Limit: 1.35A (Typ)
- Output Noise from 10Hz to 10KHz: 0.003% of Vout
- PSRR at I<sub>OUT</sub> = 300mA and f = 120Hz: 70dB
- Output Voltage Accuracy: ±1% (Except 1.2V Version)
- On-chip Thermal Shutdown
- Maximum Quiescent Current: IQMAX = 6mA
- Compatible with Low ESR Ceramic Capacitor
- Operation Junction Temperature: -40°C to +125°C
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

# Pin Assignments



TO252 (Type CJ)

### Applications

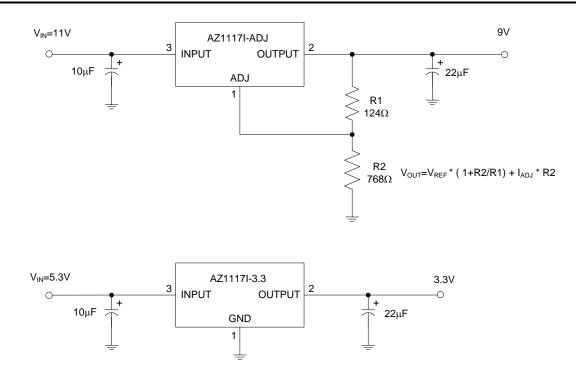
- USB devices
- Add-on cards
- DVD players
- PC motherboards

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

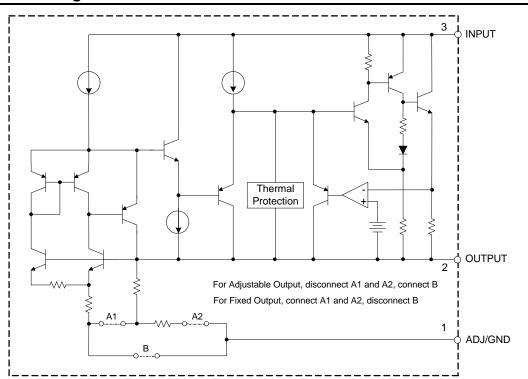


## Typical Applications Circuit (Note 4)



Note: 4. The AZ1117I is compatible with low ESR ceramic capacitor. The ESR of the output capacitors must be less than 20Ω. A minimum of 10µF output capacitor is required.

## **Functional Block Diagram**





### Absolute Maximum Ratings (Note 5) (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Symbol	Parameter	Parameter Rating		Unit	
V <sub>IN</sub>	Input Voltage	18		V	
TJ	Operating Junction Temperature Range	+150		°C	
T <sub>STG</sub>	Storage Temperature Range	-65 to +150		°C	
θ <sub>JA</sub>	Thermal Resistance (Without Heatsink)	SOT223	125	°C/W	
UJA		TO252-2	100		
θ <sub>JA</sub>	Thermal Resistance (With Heatsink) (Note 6)	SOT223	100	°C/W	
OJA		TO252-2	70		
T <sub>LEAD</sub>	Lead Temperature (Soldering, 10sec)	+260		°C	

Notes: 5. Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability. 6. Chip is soldered to 100mm<sup>2</sup>(10mm\*10mm) copper (top side solder mask) on 2oz.2 layers FR-4 PCB with 8\*0.5mm vias.

### Recommended Operating Conditions (@TA = +25°C, unless otherwise specified.)

Symbol	Parameter	Min	Max	Unit
V <sub>IN</sub>	Input Voltage	-	15	V
TJ	Operating Junction Temperature Range	-40	+125	°C

### **Electrical Characteristics AZ1117I-ADJ**

(Operating Conditions: V<sub>IN</sub> = V<sub>OUT</sub>+2V, I<sub>OUT</sub> = 10mA, T<sub>J</sub> = +25°C, unless otherwise specified. (P ≤ maximum power dissipation). Limits appearing in **Boldface** type apply over the entire junction temperature range for operation, -40°C to +125°C.)

Symbol	Parameter	Con	ditions	Min	Тур	Max	Unit
M	Reference Voltage		< 10)/	1.238	1.250	1.262	V
$V_{REF}$	Reference voltage	1.5V ≤ V <sub>IN</sub> -V <sub>OUT</sub> ≤	≤ 10V	1.225	1.250	1.275	v
V <sub>RLINE</sub>	Line Regulation	$1.5V \leq V(u, V)$	$1.5V \le V_{IN} \cdot V_{OUT} \le 10V$		0.001	0.1	%
V RLINE					—	0.2	/0
V <sub>RLOAD</sub>	Load Regulation	$V_{IN} = V_{OUT}+2V$	1mA ≤ I <sub>OUT</sub> ≤ 1A	—	0.4	1.0	%
N/	Dropout Voltage	$\Delta V_{REF} = 1\%,$	SOT223	—	1.2	1.3	V
V <sub>DROP</sub>	Diopout voltage	$I_{OUT} = 0.8A$			1.3	1.4	V
ILIMIT	Current Limit	—	_		1.35	_	А
_	Adjust Pin Current	—	—		60	120	μA
—	Adjust Pin Current Change	1.5 ≤ (V <sub>IN</sub> -V <sub>OUT</sub> ) ≤	$1.5 \le (V_{IN} - V_{OUT}) \le 10V$		0.2	5	μA
_	Minimum Load Current	1.5 ≤ (V <sub>IN</sub> -V <sub>OUT</sub> ) ≤	≤ 10V	_	1.7	5	mA
PSRR	Ripple Rejection	f = 120Hz, C <sub>OUT</sub> = (V <sub>IN</sub> -V <sub>OUT</sub> ) = 3V,		_	70	_	dB
_	Temperature Stability	—		_	0.5	_	%
	RMS Output Noise (% of V <sub>OUT</sub> )	T <sub>A</sub> = +25°C, 10Hz	z ≤ f ≤ 10KHz	_	0.003	—	%
	Thermal Shutdown	Junction Tempera	ature	—	+160	_	°C
_	Thermal Shutdown Hysteresis	—	· · ·		+16	—	°C
	Thermal Desistance			_		_	
θ <sub>JC</sub>	Thermal Resistance (Junction to Case)	SOT223			15		°C/W
		TO252-2		_	10	_	



## **Electrical Characteristics AZ1117I-1.2**

(Operating Conditions:  $V_{IN} \le 10V$ ,  $I_{OUT} = 10mA$ ,  $T_J = +25^{\circ}C$ , unless otherwise specified. (P  $\le$  maximum power dissipation). Limits appearing in **Boldface** type apply over the entire junction temperature range for operation, -40°C to +125°C.)

Symbol	Parameter	Con	ditions	Min	Тур	Max	Unit
N/	Output Maltana		401	1.176	1.2	1.224	V
Vout	Output Voltage	$1.5V \leq VIN-VOUT \leq$	$1.5V \le V_{IN} \cdot V_{OUT} \le 10V$		1.2	1.248	v
M	Line Regulation		(10)/	—	0.5	6	mV
V <sub>RLINE</sub>		1.5V ≤ V <sub>IN</sub> -V <sub>OUT</sub> ≤	10V	—	—	10	IIIV
Vrload	Load Regulation	$V_{IN} = V_{OUT} + 2V$	1mA ≤ I <sub>OUT</sub> ≤ 1A	—	2	15	mV
N/		$\Delta V_{OUT} = 1\%,$	SOT223	—	1.2	1.3	V
Vdrop	Dropout Voltage	I <sub>OUT</sub> = 0.8A	TO252-2	—	1.3	1.4	V
I <sub>LIMIT</sub>	Current Limit	—	—		1.35	_	А
lq	Quiescent Current	$I_{OUT} = 0$	I <sub>OUT</sub> = 0		4	6	mA
PSRR	Ripple Rejection	f = 120Hz, C <sub>OUT</sub> =	$f = 120Hz, C_{OUT} = 22\mu F$ (V <sub>IN</sub> -V <sub>OUT</sub> ) = 3V, I <sub>OUT</sub> = 300mA		70	_	dB
1 OKK		$(V_{IN}-V_{OUT}) = 3V, I$			70		uВ
_	Temperature Stability	—		—	0.5	—	%
—	RMS Output Noise (% of V <sub>OUT</sub> )	T <sub>A</sub> = +25°C, 10Hz	:≤f≤10KHz	—	0.003	—	%
	Thermal Shutdown	Junction Tempera	ature	—	+160	_	°C
_	Thermal Shutdown Hysteresis			—	+16	_	°C
				_		_	
θ <sub>JC</sub>	Thermal Resistance (Junction to Case)	SOT223	SOT223		15	—	°C/W
		TO252-2		_	10	_	

### **Electrical Characteristics AZ1117I-1.5**

(Operating Conditions:  $V_{IN} \le 10V$ ,  $I_{OUT} = 10mA$ ,  $T_J = +25^{\circ}C$ , unless otherwise specified. (P  $\le$  maximum power dissipation). Limits appearing in **Boldface** type apply over the entire junction temperature range for operation, -40°C to +125°C.)

Symbol	Parameter	Con	ditions	Min	Тур	Max	Unit
M			< 10)/	1.485	1.5	1.515	V
Vout	Output Voltage	$1.5V \le V_{IN} - V_{OUT} \le 10V$		1.47	1.5	1.53	v
N/	Line Regulation		< 10)/	—	0.5	6	mV
V <sub>RLINE</sub>		1.5V ≤ V <sub>IN</sub> -V <sub>OUT</sub> ≤	≤ 10V	—	—	10	IIIV
V <sub>RLOAD</sub>	Load Regulation	$V_{IN} = V_{OUT}+2V$	1mA ≤ I <sub>OUT</sub> ≤ 1A	—	2	15	mV
M	Dranout Vieltage	$\Delta V_{OUT} = 1\%,$	SOT223	—	1.2	1.3	V
Vdrop	Dropout Voltage	I <sub>OUT</sub> = 0.8A	TO252-2	—	1.3	1.4	V
ILIMIT	Current Limit			1	1.35	—	А
lq	Quiescent Current	$I_{OUT} = 0$	$I_{OUT} = 0$		4	6	mA
PSRR	Ripple Rejection	$f = 120Hz, C_{OUT} = (V_{IN}-V_{OUT}) = 3V,$		_	70	_	dB
_	Temperature Stability		1001 – 300IIIA		0.5		%
_	RMS Output Noise (% of V <sub>OUT</sub> )	T <sub>A</sub> = +25°C, 10Hz	z ≤ f ≤ 10KHz	_	0.003	_	%
_	Thermal Shutdown	Junction Tempera	ature	_	+160	_	°C
_	Thermal Shutdown Hysteresis			—	+16	_	°C
	Thermol Desistance			—		_	
$\theta_{\text{JC}}$	Thermal Resistance (Junction to Case)	SOT223			15		°C/W
		TO252-2	TO252-2		10	_	



## **Electrical Characteristics AZ1117I-1.8**

(Operating Conditions:  $V_{IN} \le 10V$ ,  $I_{OUT} = 10mA$ ,  $T_J = +25$ °C, unless otherwise specified. (P  $\le$  maximum power dissipation). Limits appearing in **Boldface** type apply over the entire junction temperature range for operation, -40°C to +125°C.)

Symbol	Parameter	Con	ditions	Min	Тур	Max	Unit
	Output Maltana		401/	1.782	1.8	1.818	V
Vout	Output Voltage	$1.5V \leq VIN-VOUT \leq$	$1.5V \le V_{IN} \cdot V_{OUT} \le 10V$		1.8	1.836	v
M	Line Regulation		101/	—	0.5	6	mV
V <sub>RLINE</sub>		1.5V ≤ V <sub>IN</sub> -V <sub>OUT</sub> ≤	100	—	—	10	IIIV
Vrload	Load Regulation	$V_{IN} = V_{OUT} + 2V$	1mA ≤ I <sub>OUT</sub> ≤ 1A	—	2	15	mV
N/		$\Delta V_{OUT} = 1\%$ ,	SOT223	—	1.2	1.3	V
Vdrop	Dropout Voltage	I <sub>OUT</sub> = 0.8A	TO252-2	_	1.3	1.4	V
I <sub>LIMIT</sub>	Current Limit	—	_		1.35	—	А
lq	Quiescent Current	I <sub>OUT</sub> = 0		_	4	6	mA
PSRR	Ripple Rejection	f = 120Hz, C <sub>OUT</sub> =	f = 120Hz, C <sub>OUT</sub> = 22µF (V <sub>IN</sub> -V <sub>OUT</sub> ) = 3V, I <sub>OUT</sub> = 300mA		70	_	dB
1 OKK		$(V_{IN}-V_{OUT}) = 3V, I$			70	—	uБ
_	Temperature Stability	—		—	0.5	—	%
—	RMS Output Noise (% of V <sub>OUT</sub> )	T <sub>A</sub> = +25°C, 10Hz	≤ f ≤ 10KHz	—	0.003	—	%
_	Thermal Shutdown	Junction Tempera	iture	_	+160	_	°C
_	Thermal Shutdown Hysteresis			—	+16	_	°C
	The word Desistance			_		_	
θ <sub>JC</sub>	Thermal Resistance (Junction to Case)	SOT223	SOT223		15	_	°C/W
		TO252-2		_	10	_	

### **Electrical Characteristics AZ1117I-2.5**

(Operating Conditions:  $V_{IN} \le 10V$ ,  $I_{OUT} = 10mA$ ,  $T_J = +25$ °C, unless otherwise specified. (P  $\le$  maximum power dissipation). Limits appearing in **Boldface** type apply over the entire junction temperature range for operation, -40°C to +125°C.)

Symbol	Parameter	Con	ditions	Min	Тур	Max	Unit
			( 40) (	2.475	2.5	2.525	V
Vout	Output Voltage	$1.5V \le V_{IN} - V_{OUT} \le 10V$		2.455	2.5	2.545	V
N/	Line Regulation		: 10)/	—	0.5	6	mV
V <sub>RLINE</sub>		1.5V ≤ V <sub>IN</sub> -V <sub>OUT</sub> ≤	≤ 10V	—		10	IIIV
V <sub>RLOAD</sub>	Load Regulation	$V_{IN} = V_{OUT} + 2V$	1mA ≤ I <sub>OUT</sub> ≤ 1A	—	2	15	mV
N/		$\Delta V_{OUT} = 1\%,$	SOT223	—	1.2	1.3	V
Vdrop	Dropout Voltage	I <sub>OUT</sub> = 0.8A	TO252-2	_	1.3	1.4	V
ILIMIT	Current Limit	_		1	1.35	—	А
lq	Quiescent Current	$I_{OUT} = 0$		—	4	6	mA
PSRR	Ripple Rejection	f = 120Hz, C <sub>OUT</sub> = (V <sub>IN</sub> -V <sub>OUT</sub> ) = 3V,		_	70	_	dB
	Temperature Stability	—		_	0.5		%
—	RMS Output Noise (% of V <sub>OUT</sub> )	T <sub>A</sub> = +25°C, 10Hz	z ≤ f ≤ 10KHz	_	0.003	_	%
_	Thermal Shutdown	Junction Tempera	ature	—	+160		°C
	Thermal Shutdown Hysteresis			_	+16		°C
	Thermel Desistence	0.07000		_		_	
$\theta_{JC}$	Thermal Resistance (Junction to Case)	SOT223	SOT223		15		°C/W
		TO252-2			10	_	



## **Electrical Characteristics AZ1117I-3.3**

(Operating Conditions:  $V_{IN} \le 10V$ ,  $I_{OUT} = 10mA$ ,  $T_J = +25^{\circ}C$ , unless otherwise specified. (P  $\le$  maximum power dissipation). Limits appearing in **Boldface** type apply over the entire junction temperature range for operation, -40°C to +125°C.)

Symbol	Parameter	Cor	ditions	Min	Тур	Max	Unit
			< 10)/	3.267	3.3	3.333	V
Vout	Output Voltage	$1.5V \le V_{IN} - V_{OUT} \le 10V$		3.235	3.3	3.365	v
<b>M</b>	Line Regulation	1.5V ≤ V <sub>IN</sub> -V <sub>OUT</sub>	< 10\/	_	0.5	6	mV
V <sub>RLINE</sub>		$1.5V \leq V N - V OU$	r = 10V		_	10	IIIV
Vrload	Load Regulation	$V_{IN} = V_{OUT} + 2V$	1mA ≤ I <sub>OUT</sub> ≤ 1A	—	2	15	mV
\/	Dropout Voltage	$\Delta V_{OUT} = 1\%,$	SOT223	_	1.2	1.3	V
Vdrop	Dropout Voltage	$I_{OUT} = 0.8A$	TO252-2	_	1.3	1.4	V
I <sub>LIMIT</sub>	Current Limit	—		1	1.35	_	А
lq	Quiescent Current	$I_{OUT} = 0$			4	6	mA
PSRR	Ripple Rejection	f = 120Hz, C <sub>OUT</sub>	$f = 120Hz, C_{OUT} = 22\mu F$ (V <sub>IN</sub> -V <sub>OUT</sub> ) = 3V, I <sub>OUT</sub> = 300mA		70	_	dB
FORK		$(V_{IN}-V_{OUT}) = 3V$			70		
_	Temperature Stability	—		_	0.5	_	%
—	RMS Output Noise (% of V <sub>OUT</sub> )	T <sub>A</sub> = +25°C, 10H	Hz ≤ f ≤ 10KHz	_	0.003	—	%
_	Thermal Shutdown	Junction Tempe	erature	_	+160		°C
_	Thermal Shutdown Hysteresis			_	+16		°C
	Thermal Desistance			_		_	
$\theta_{JC}$	Thermal Resistance (Junction to Case)	SOT223	SOT223		15		°C/W
		TO252-2		_	10		

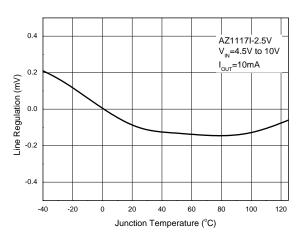
### **Electrical Characteristics AZ1117I-5.0**

(Operating Conditions:  $V_{IN} \le 10V$ ,  $I_{OUT} = 10mA$ ,  $T_J = +25^{\circ}C$ , unless otherwise specified. (P  $\le$  maximum power dissipation). Limits appearing in **Boldface** type apply over the entire junction temperature range for operation, -40°C to +125°C.)

Symbol	Parameter	Con	ditions	Min	Тур	Max	Unit
M			(10)/	4.950	5.0	5.050	V
V <sub>OUT</sub>	Output Voltage	$1.5V \ge VIN-VOUT \ge$	$1.5V \le V_{IN} - V_{OUT} \le 10V$		5.0	5.100	v
M	Line Regulation	1.5V ≤ V <sub>IN</sub> -V <sub>OUT</sub> ≤	< 10\/	—	0.5	6	mV
V <sub>RLINE</sub>		$1.5V \leq VIN^{-}VOUT \leq$	\$ 10V	—	—	10	IIIV
V <sub>RLOAD</sub>	Load Regulation	$V_{IN} = V_{OUT} + 2V$	1mA ≤ I <sub>OUT</sub> ≤ 1A	—	2	15	mV
\/	Dropout Voltage	$\Delta V_{OUT} = 1\%$ ,	SOT223	—	1.2	1.3	V
VDROP	Diopout voltage	$I_{OUT} = 0.8A$	TO252-2	—	1.3	1.4	V
ILIMIT	Current Limit	—	—		1.35	—	А
lq	Quiescent Current	$I_{OUT} = 0$	$I_{OUT} = 0$		4	6	mA
PSRR	Ripple Rejection	f = 120Hz, C <sub>OUT</sub> =	$  f = 120Hz, C_{OUT} = 22\mu F $ $  (V_{IN}-V_{OUT}) = 3V, I_{OUT} = 300mA $		70		dB
1 OKK		$(V_{IN}-V_{OUT}) = 3V,$			70		uБ
_	Temperature Stability	—		—	0.5		%
_	RMS Output Noise (% of V <sub>OUT</sub> )	T <sub>A</sub> = +25°C, 10Hz	z ≤ f ≤ 10KHz	—	0.003	—	%
_	Thermal Shutdown	Junction Tempera	ature	—	+160		°C
	Thermal Shutdown Hysteresis	_			+16	_	°C
θ <sub>JC</sub>	Thermal Resistance	SOT223		_	15		°C/W
-10	(Junction to Case)	TO252-2		_	10		27.1

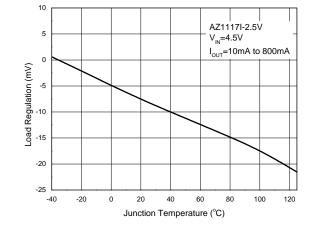


### **Performance Characteristics**

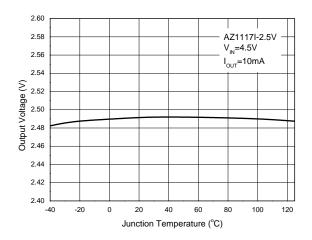


### Line Regulation vs. Temperature

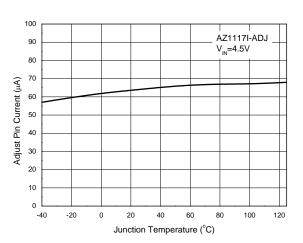
Load Regulation vs. Temperature



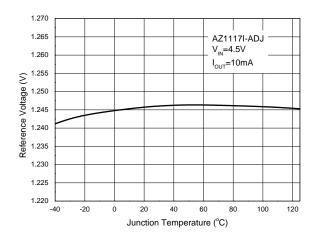
#### Output Voltage vs. Temperature



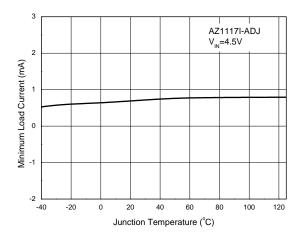




Reference Voltage vs. Temperature

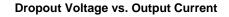


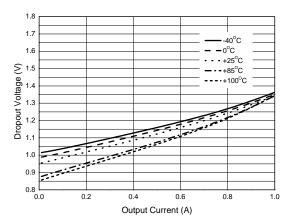
**Minimum Load Current vs. Temperature** 



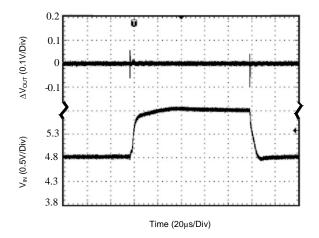


## Performance Characteristics (continued)

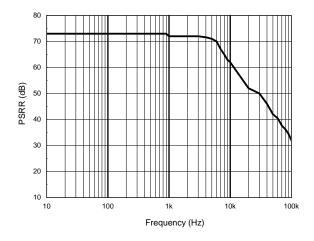




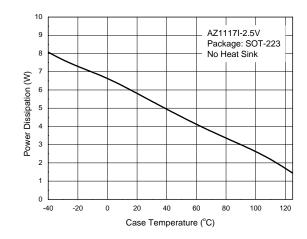
#### Line Transient Response



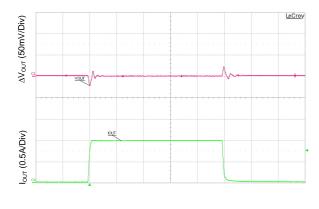
**PSRR vs. Frequency** 



Power Dissipation vs. Temperature

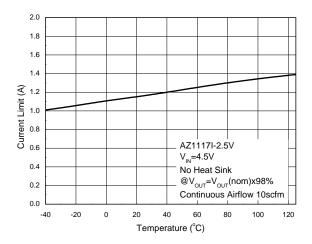


Load Transient Response



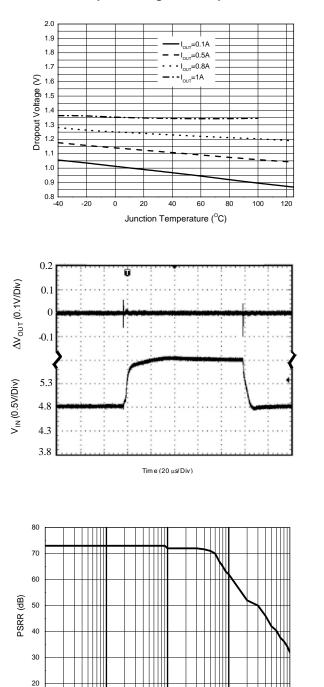
Time (10µs/Div)

#### **Current Limit vs. Temperature**





## Performance Characteristics (continued)



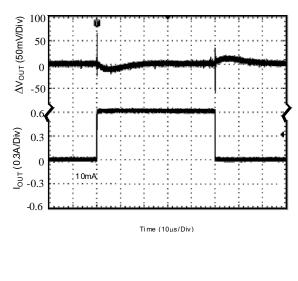
#### Dropout Voltage vs. Temperature

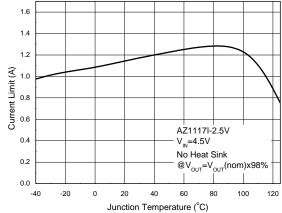
Frequency (Hz)

1k

10k

100k





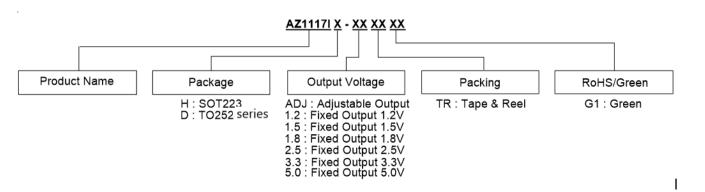
100

10

10



## **Ordering Information**



Baakana	Temperature	Orderable	Marking ID	Pac	king
Package	Range	Part Number	Marking ID	Qty.	Carrier
		AZ1117IH-ADJTRG1	GH86J	4000	Tape & Reel
		AZ1117IH-1.2TRG1	GH86K	4000	Tape & Reel
SOT223		AZ1117IH-1.5TRG1	GH86L	4000	Tape & Reel
		AZ1117IH-1.8TRG1	GH86M	4000	Tape & Reel
		AZ1117IH-2.5TRG1 GH86N		4000	Tape & Reel
		AZ1117IH-3.3TRG1	GH86P	4000	Tape & Reel
		AZ1117IH-5.0TRG1	GH86Q	4000	Tape & Reel
	-40°C to +125°C	AZ1117ID-ADJTRG1	AZ1117ID-ADJG1	2500	Tape & Reel
		AZ1117ID-1.2TRG1	AZ1117ID-1.2G1	2500	Tape & Reel
		AZ1117ID-1.5TRG1	AZ1117ID-1.5G1	2500	Tape & Reel
TO252-2 TO252 (Type CJ)		AZ1117ID-1.8TRG1	AZ1117ID-1.8G1	2500	Tape & Reel
		AZ1117ID-2.5TRG1	AZ1117ID-2.5G1	2500	Tape & Reel
		AZ1117ID-3.3TRG1	AZ1117ID-3.3G1	2500	Tape & Reel
		AZ1117ID-5.0TRG1	AZ1117ID-5.0G1	2500	Tape & Reel



### **Marking Information**

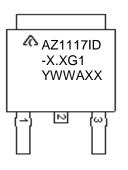
#### (1) SOT223

(Top View)

First Line: Logo and Marking ID (See Ordering Information) Second Line: Date Code Y: Year WW: Work Week of Molding A: Assembly House Code XX: 7<sup>th</sup> and 8<sup>th</sup> Digits of Batch Number

(2) TO252-2 /TO252 (Type CJ)

(Top View)



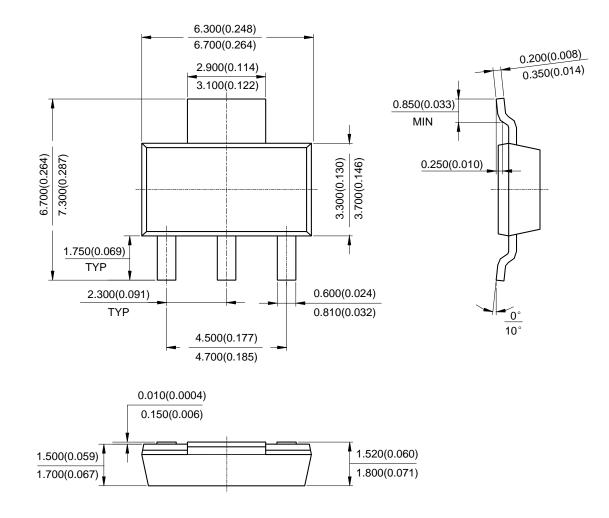
First and Second Lines: Logo and Marking ID (See Ordering Information) Third Line: Date Code Y: Year WW: Work Week of Molding A: Assembly House Code XX: 7<sup>th</sup> and 8<sup>th</sup> Digits of Batch Number



## Package Outline Dimensions (All dimensions in mm)

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### (1) Package Type: SOT223

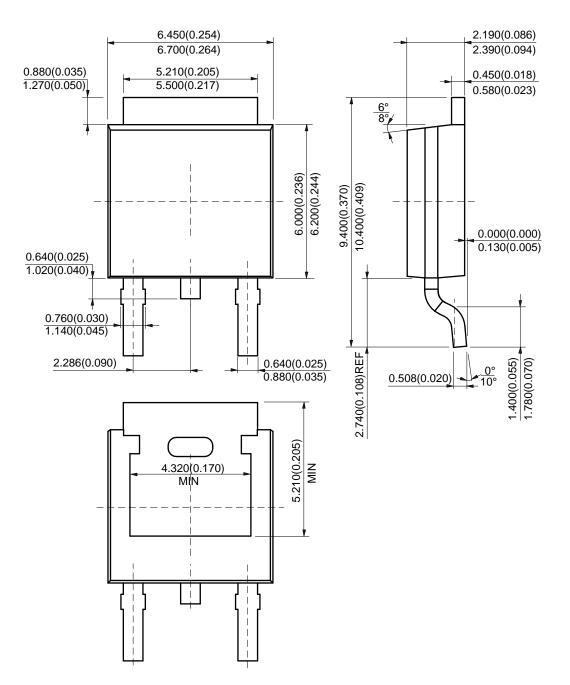




### Package Outline Dimensions (All dimensions in mm) (continued)

Please see http://www.diodes.com/package-outlines.html for the latest version.

### (2) Package Type: TO252-2 (5)

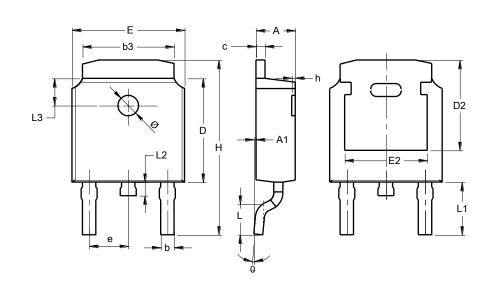




## Package Outline Dimensions (All dimensions in mm) (continued)

Please see http://www.diodes.com/package-outlines.html for the latest version.

(3) Package Type : TO252 (Type CJ)



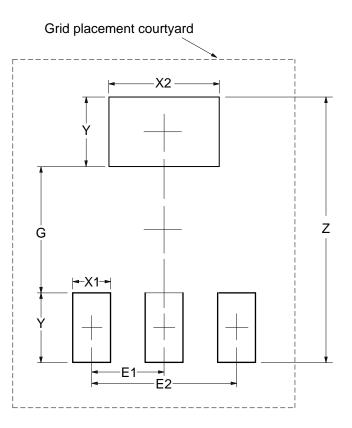
		2050						
	TO252 (Type CJ)							
Dim		,	<b>T</b>					
Dim	Min	Max	Тур					
Α	2.200	2.400						
A1	0.000	0.127						
b	0.635	0.770						
b3	5.100	5.460						
С	0.460	0.580						
D	6.000	6.200						
D2	5	.250 RE	F					
Е	6.500							
E2	4	.830 RE	F					
е	2.186	2.386						
h	0.000	0.300						
Н	9.712	10.312						
L	1.400	1.700						
L1	2	.900 RE	F					
L2	0.600	1.000						
L3	1	.600 RE	F					
Ø	1.100	1.300						
θ	0°	8°						
AI	l Dimen	sions in	mm					



## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### (1) Package Type: SOT223



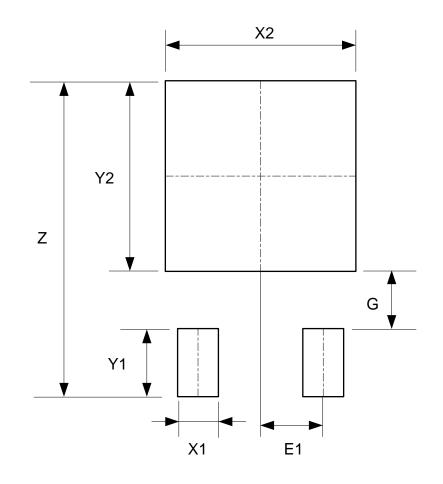
Dimensions	Z	G	X1	X2	Y	E1	E2
	(mm)/(inch)						
Value	8.400/0.331	4.000/0.157	1.200/0.047	3.500/0.138	2.200/0.087	2.300/0.091	4.600/0.181



## Suggested Pad Layout (continued)

Please see http://www.diodes.com/package-outlines.html for the latest version.

(2) Package Type: TO252-2 (5) / TO252 (Type CJ)



Dimensions	Z	X1	X2=Y2	Y1	G	E1
	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)
Value	11.600/0.457	1.500/0.059	7.000/0.276	2.500/0.098	2.100/0.083	2.300/0.091

### **Mechanical Data**

- Moisture Sensitivity: Level 3 per J-STD-020
- Terminals: Finish— Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 🔞
- Weight:
  - TO-252-2 / TO252 (Type CJ): 0.312 grams (Approximate)
  - SOT-223: 0.116 grams (Approximate)



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